









CSD85301Q2 SLPS521A - DECEMBER 2014 - REVISED MAY 2024

CSD85301Q2 20V Dual N-Channel NexFET™ Power MOSFETs

1 Features

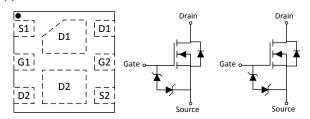
- Low on-resistance
- **Dual independent MOSFETs**
- Space saving SON 2mm × 2mm plastic package
- Optimized for 5V gate driver
- Avalanche rated
- Pb and halogen free
- RoHS compliant

2 Applications

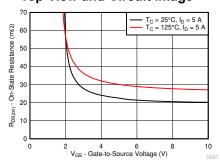
- Point-of-load synchronous buck converter for applications in networking, telecom, and computing systems
- Adaptor or USB input protection for notebook PCs and tablets
- **Battery protection**

3 Description

The CSD85301Q2 is a 20V, $23m\Omega$ N-Channel device with dual independent MOSFETs in a SON 2mm x 2mm plastic package. The two FETs were designed to be used in a half bridge configuration for synchronous buck and other power supply applications. Additionally, this part can be used for adaptor, USB input protection and battery charging applications. The dual FETs feature low drain to source on-resistance that minimizes losses and offers low component count for space constrained applications.



Top View and Circuit Image



R_{DS(on)} vs V_{GS}

Product Summary

T _A = 25°	C	TYPICAL VA	UNIT		
V _{DS}	Drain-to-Source Voltage	20	20		
Qg	Gate Charge Total (4.5V)	4.2		nC	
Q _{gd}	Gate Charge Gate to Drain	rge Gate to Drain 1.0			
		V _{GS} = 1.8V	65	mΩ	
B	Drain-to-Source On Resistance	V _{GS} = 2.5V	33	mΩ	
R _{DS(on)}	Dialii-to-Source Off Resistance	V _{GS} = 3.8V	25	mΩ	
		V _{GS} = 4.5V	23	mΩ	
V _{GS(th)}	Threshold Voltage	0.9			

Ordering Information

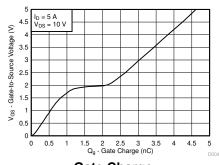
Device ⁽¹⁾	Media	Qty	Package	Ship
CSD85301Q2	7-Inch Reel	3000	SON 2mm x	Tape and
CSD85301Q2T	7-Inch Reel	250	2mm Plastic Package	Reel

For all available packages, see the orderable addendum at (1) the end of the data sheet.

Absolute Maximum Ratings

T _A = 2	5°C	VALUE	UNIT
V _{DS}	Drain-to-Source Voltage	20	V
V _{GS}	Gate-to-Source Voltage	±10	V
I _D	Continuous Drain Current (Package limited)	5.0	Α
I _{DM}	Pulsed Drain Current ⁽¹⁾	26	Α
P _D	Power Dissipation ⁽²⁾	2.3	W
T _J , T _{stg}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse I_D = 8.7A, L = 0.1mH, R_G = 25 Ω	3.8	mJ

- Max R_{θJA} = 185 °C/W, pulse duration ≤100μs, duty cycle (1)
- (2)Typical $R_{\theta JA}$ = 55 °C/W on a 1 inch², 2oz. Cu pad on a 0.06 inch thick FR4 PCB.



Gate Charge



Table of Contents

4 =	50 T
1 Features1	5.3 Trademarks7
2 Applications 1	5.4 Electrostatic Discharge Caution7
3 Description1	
4 Specifications3	6 Revision History
4.1 Electrical Characteristics3	7 Mechanical, Packaging, and Orderable Information
4.2 Thermal Information3	7.1 Package Dimensions9
4.3 Typical MOSFET Characteristics4	7.2 PCB Land Pattern10
5 Device and Documentation Support7	7.3 Recommended Stencil Opening
5.1 Receiving Notification of Documentation Updates7	7.4 Q2 Tape and Reel Information11
5.2 Support Resources7	·

4 Specifications

4.1 Electrical Characteristics

(T_A = 25°C unless otherwise stated)

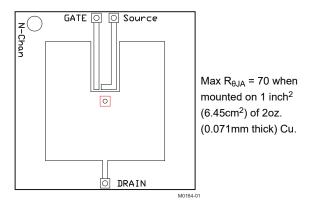
	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
STATIC	CHARACTERISTICS				
BV _{DSS}	Drain-to-Source Voltage	V _{GS} = 0V, I _D = 250μA	20		V
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0V, V _{DS} = 16V		1	μA
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0V, V _{GS} = 10V		10	μA
V _{GS(th)}	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	0.6 0.9	1.2	V
		V _{GS} = 1.8V, I _D = 0.5A	65	99	mΩ
В	Drain to Source On Resistance	$V_{GS} = 2.5V, I_D = 5A$	33	39	mΩ
R _{DS(on)}	Drain-to-Source On-Resistance	$V_{GS} = 3.8V, I_D = 5A$	25	29	mΩ
		$V_{GS} = 4.5V, I_D = 5A$	23	27	mΩ
g _{fs}	Transconductance	$V_{DS} = 2V, I_{D} = 5A$	20		S
DYNAM	IC CHARACTERISTICS		<u> </u>		
C _{iss}	Input Capacitance		361	469	pF
Coss	Output Capacitance	$V_{GS} = 0V, V_{DS} = 10V, f = 1MHz$	68	89	pF
C _{rss}	Reverse Transfer Capacitance		48	62	pF
R _G	Series Gate Resistance		7.3		Ω
Qg	Gate Charge Total (4.5V)		4.2	5.4	nC
Q _{gd}	Gate Charge Gate-to-Drain	\\ -10\\ -50	1.0		nC
Q _{gs}	Gate Charge Gate-to-Source	$V_{DS} = 10V, I_D = 5A$	1.1		nC
Q _{g(th)}	Gate Charge at V _{th}		0.5		nC
Q _{oss}	Output Charge	V _{DS} = 10V, V _{GS} = 0V	1.3		nC
t _{d(on)}	Turn On Delay Time		6		ns
t _r	Rise Time	V _{DS} = 10V, V _{GS} = 5V,	26		ns
$t_{d(off)}$	Turn Off Delay Time	$I_{DS} = 5A$, $R_G = 0\Omega$	14		ns
t _f	Fall Time		15		ns
DIODE (CHARACTERISTICS			'	
V _{SD}	Diode Forward Voltage	I _{SD} = 5A, V _{GS} = 0V	0.8	1.0	V
Q _{rr}	Reverse Recovery Charge	V _{DS} = 10V, I _F = 5A,	7.2		nC
t _{rr}	Reverse Recovery Time	di/dt = 300A/µs	14		ns

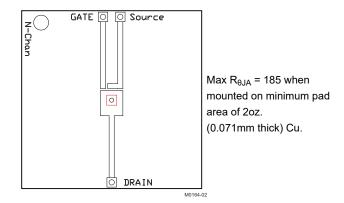
4.2 Thermal Information

	THERMAL METRIC	MIN	TYP	MAX	UNIT
D	Junction-to-Ambient Thermal Resistance ⁽¹⁾			70	°C/W
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance ⁽²⁾			185	C/VV

 ⁽¹⁾ Device mounted on FR4 material with 1 inch² (6.45cm²), 2oz. (0.071mm thick) Cu.
 (2) Device mounted on FR4 material with minimum Cu mounting area.







4.3 Typical MOSFET Characteristics

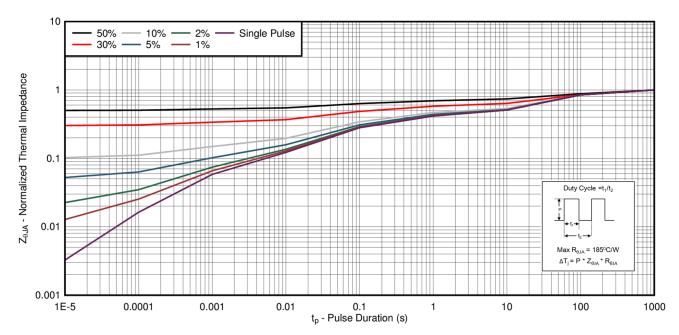
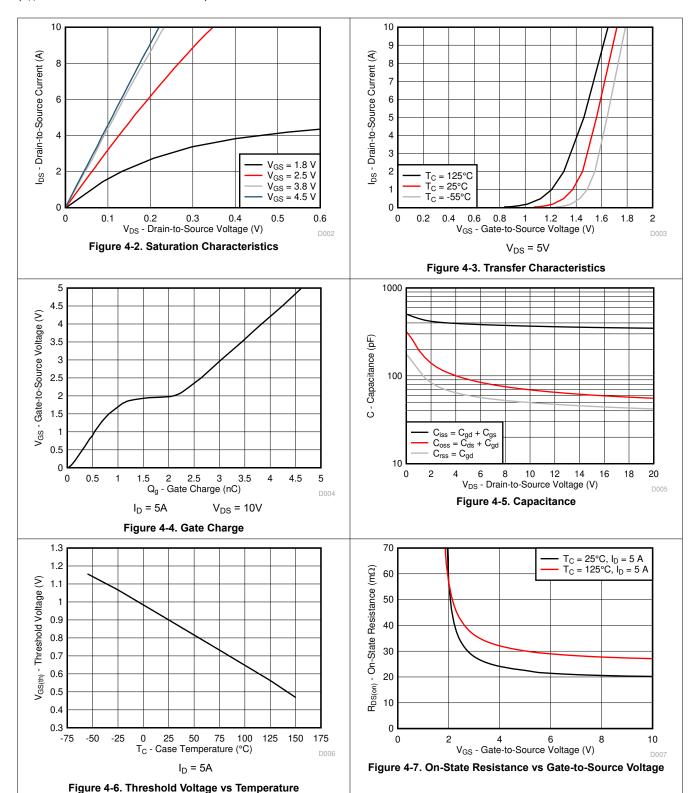


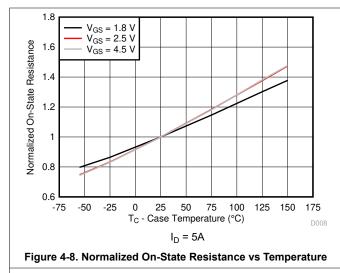
Figure 4-1. Transient Thermal Impedance



4.3 Typical MOSFET Characteristics (continued)



4.3 Typical MOSFET Characteristics (continued)



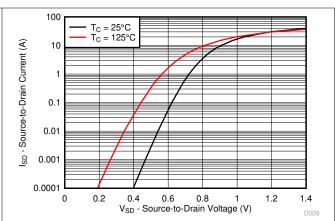
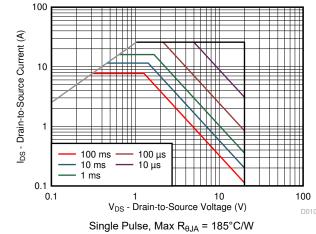


Figure 4-9. Typical Diode Forward Voltage



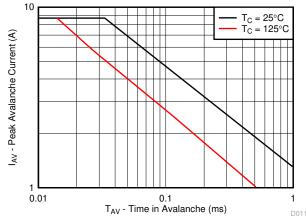


Figure 4-10. Maximum Safe Operating Area



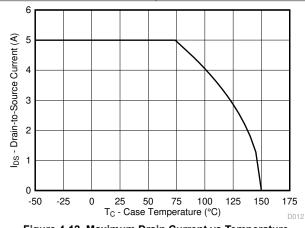


Figure 4-12. Maximum Drain Current vs Temperature

5 Device and Documentation Support

5.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

5.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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5.3 Trademarks

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5.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

5.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.



6 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	Changes from Revision * (December 2014) to Revision A (May 2024)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1

Submit Document Feedback

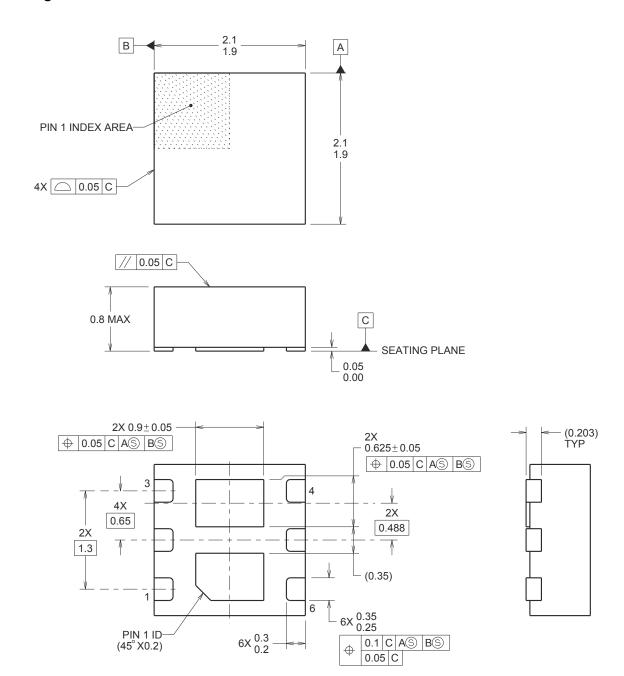
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7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

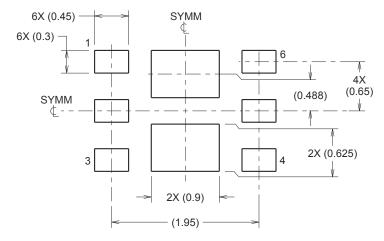
7.1 Package Dimensions



All dimensions are in mm, unless otherwise stated.

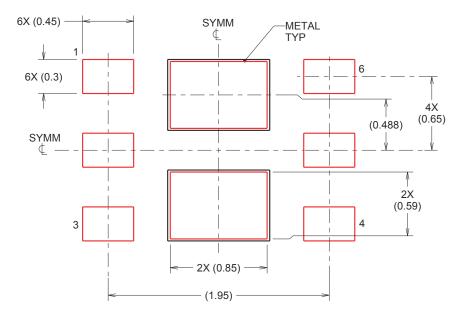


7.2 PCB Land Pattern



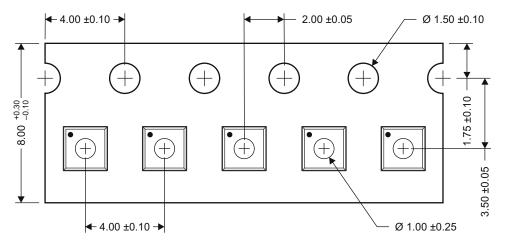
For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

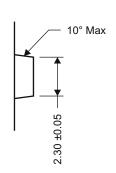
7.3 Recommended Stencil Opening

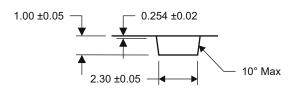


All dimensions are in mm, unless otherwise stated.

7.4 Q2 Tape and Reel Information







M0168-01

- 1. Measured from centerline of sprocket hole to centerline of pocket
- 2. Cumulative tolerance of 10 sprocket holes is ±0.20
- 3. Other material available
- 4. Typical SR of form tape Max 109 OHM/SQ
- 5. All dimensions are in mm, unless otherwise specified.

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
CSD85301Q2	Active	Production	WSON (DLV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 150	8531
CSD85301Q2.B	Active	Production	WSON (DLV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 150	8531
CSD85301Q2G4.B	Active	Production	WSON (DLV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 150	8531
CSD85301Q2T	Active	Production	WSON (DLV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 150	8531
CSD85301Q2T.B	Active	Production	WSON (DLV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 150	8531

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD85301Q2	WSON	DLV	6	3000	180.0	9.5	2.3	2.3	1.0	4.0	8.0	Q1
CSD85301Q2T	WSON	DLV	6	250	180.0	9.5	2.3	2.3	1.0	4.0	8.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD85301Q2	WSON	DLV	6	3000	189.0	185.0	36.0
CSD85301Q2T	WSON	DLV	6	250	189.0	185.0	36.0

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